

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE55P30 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

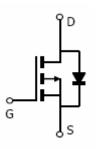
General Features

- V_{DS} =-55V, I_{D} =-30A $R_{DS(ON)}$ <40m Ω @ V_{GS} =-10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!



Schematic diagram



Marking and pin assignment



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE55P30	NCE55P30	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-55	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	-30	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	-21	А
Pulsed Drain Current	I _{DM}	110	А
Maximum Power Dissipation	P _D	90	W
Derating factor		0.72	W/°C
Single pulse avalanche energy (Note 5)	E _{AS}	420	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 150	$^{\circ}$

NCE55P30

Thermal Characteristic

Thermal Resistance,Junction-to-Case ^(Note 2)	R _{eJC}	1.39	°C/W	
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Electrical Characteristics (T_C=25°C unless otherwise noted)

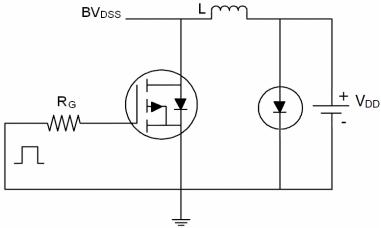
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-55	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-55V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250μA	-2	-2.6	-4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-15A	-	30	40	mΩ
Forward Transconductance	g fs	V _{DS} =-25V,I _D =-16A	8	-	-	S
Dynamic Characteristics (Note4)	<u>.</u>		•			
Input Capacitance	C _{lss})/ 00)/)/ 0)/	-	3500	-	PF
Output Capacitance	C _{oss}	V_{DS} =-30V, V_{GS} =0V, F=1.0MHz	-	240	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIDZ	-	153	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	12	-	nS
Turn-on Rise Time	t _r	V _{DD} =-30V,I _D =-15A	-	15	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-10 V , R_{GEN} =3 Ω	-	38	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg	\/ - 44\/ - 164	-	56	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-44V, I_{D} =-16A, V_{GS} =-10V	-	11	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} 10V	-	24	-	nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-24A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-30	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = -15A	-	-	71	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	-	170	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

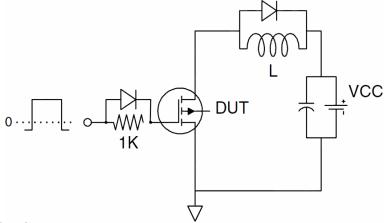
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** E_{AS} condition: $Tj=25^{\circ}C$, V_{DD} =-25V, V_{G} =-20V,L=1mH, $Rg=25\Omega$, I_{AS} =29A

Test Circuit

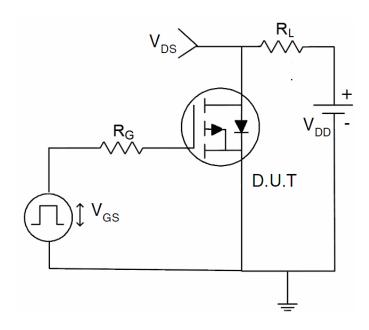
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

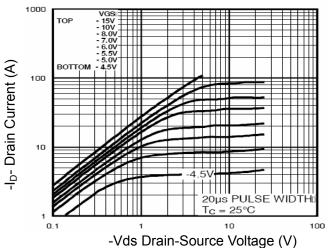


Figure 1 Output Characteristics

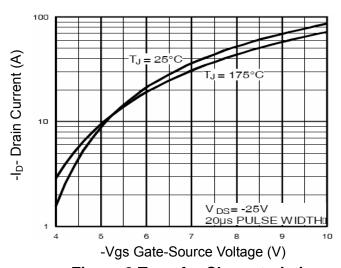
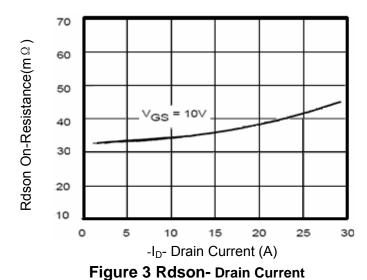


Figure 2 Transfer Characteristics



2.0 Volume 1.5 1.5 1.0 Volume 1.0

Figure 4 Rdson-JunctionTemperature

T_J-Junction Temperature(°C)

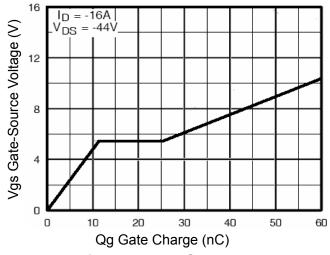


Figure 5 Gate Charge

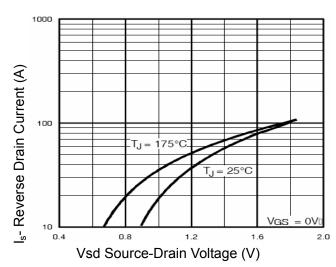
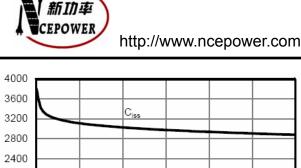


Figure 6 Source- Drain Diode Forward



C Capacitance (pF)

2000 1600

1200 800

> 400 0

> > 0

Vds Drain-Source Voltage (V) Figure 7 Capacitance vs Vds

25

30

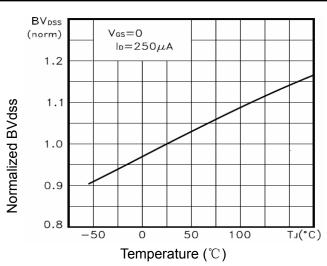


Figure 9 BV_{DSS} vs Junction Temperature

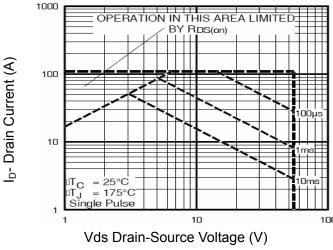


Figure 8 Safe Operation Area

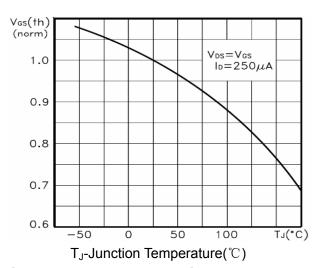


Figure 10 V_{GS(th)} vs Junction Temperature

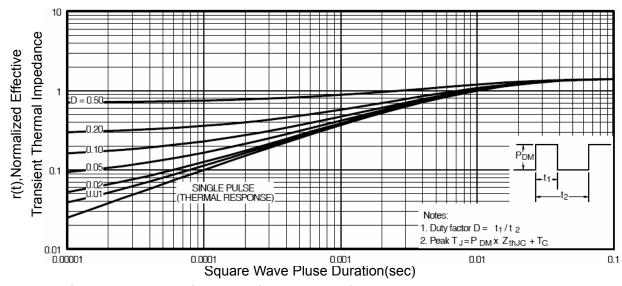
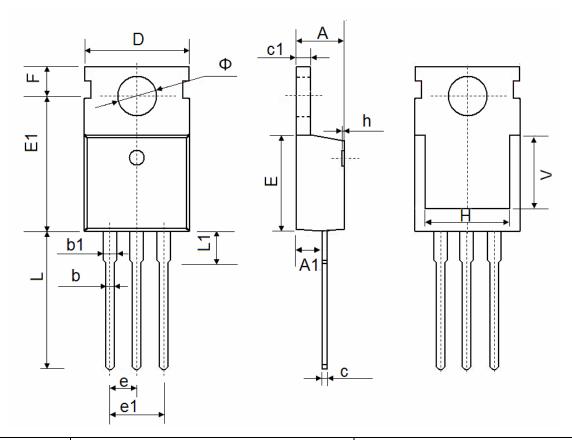


Figure 11 Normalized Maximum Transient Thermal Impedance

TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Ф	3.400	3.800	0.134	0.150	

http://www.ncepower.com

NCE55P30

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